2026/2027 MPW schedule

Last updated: November 05, 2026

MPW name	Fab	Processes	Tape-In	Ship Date
CA18 - B6407	**NPB - Fab 3**	RFCMOS 0.18um	**4-28-26**	**11-05-26**
PH18M* - B6408	**NPB - Fab 3**	SiPho 0.18um	**5-12-26**	**1-04-27**
SB*18 - B6412	**NPB - Fab 3**	SiGe BiCMOS 0.18um	**7-14-26**	**2-01-27**
CA18 - B6413	**NPB - Fab 3**	RFCMOS 0.18um	**7-28-26**	**1-08-27**
PH18M* - B6414	**NPB - Fab 3**	SiPho 0.18um	**8-11-26**	**04-05-27**
38th MPW - Tonami, Japan	**TPSCo - Fab 5**	CMOS 0.18u & 0.16u, PM, PM_SOI	**8-24-26**	**
SB*18 - B6415	**NPB - Fab 3**	SiGe BiCMOS 0.18um	**8-25-26**	**3-04-27**
2nd MPW RFSOI-RSS6T	**TSIT - Fab 10**	90RSC/65RSA2/65RSB2/65RSC	**9-10-26**	**
SBC18HE5PCA - B6416	**NPB - Fab 3**	SiGe BiCMOS 0.18um with PCM RF Switch	**9-15-26**	**
40th MPW - Uozu, Japan	**TPSCo - Fab 7**	CMOS, PM, RFCMOS & SiGe, 65nm : TPS65SLA/SLC, TPS65PMA/PMB/PMC/PMD/PMK/PML/MSA/MSB/MSC/MSD/MSK/MSL, TPS65RF, TPS65SG	**9-28-26**	**
SB*18 - B6417	**NPB - Fab 3**	SiGe BiCMOS 0.18um	**10-6-26**	**4-15-27**
41th MPW - Uozu, Japan	**TPSCo - Fab 7**	300mm Silicon Photonics: TPS45PHD	**10-26-26**	**
PH18M* - B6418	**NPB - Fab 3**	SiPho 0.18um	**10-27-26**	**6-21-27**
SH226T18NOV	**MH - Fab 2**	CIS 0.18u Image Sensor CMOS+ 0.16u, 0.18u RF, RFID, PM	**11-10-26** **11-17-26**	**
39th MPW - Tonami, Japan	**TPSCo - Fab 5**	CMOS 0.18u & 0.16u, PM, PM_SOI	**11-24-26**	**
SB*18 - B6700	**NPB - Fab 3**	SiGe BiCMOS 0.18um	**1-19-27**	**7-29-27**
CA18 - B6701	**NPB - Fab 3**	RFCMOS 0.18um	**2-02-27**	**7-16-27**
PH18M* - B6702	**NPB - Fab 3**	SiPho 0.18um	**2-16-27**	**10-11-27**
40th MPW - Tonami, Japan	**TPSCo - Fab 5**	CMOS 0.18u & 0.16u, PM, PM_SOI	**2-24-27**	**
SB*18 - B6703	**NPB - Fab 3**	SiGe BiCMOS 0.18um	**3-02-27**	**9-09-27**
PH18DA - B6704	**NPB - Fab 3**	SiPho 0.18um	**3-16-27**	**1-14-28**

MPW name	Fab	Processes	Tape-In	Ship Date
42nd MPW - Uozu, Japan	**TPSCo - Fab 7**	CMOS, PM, RFCMOS & SiGe, 65nm : TPS65SLA/SLC, TPS65PMA/PMB/PMC/PMD/PMK/PML/MSA/MSB/MSC/MSD/MSK/MSL, TPS65RF, TPS65SG	**3-23-27**	**
SBC18S6MPCA - B6705	**NPB - Fab 3**	SiGe BiCMOS 0.18um with PCM RF Switch	**3-30-27**	**
43rd MPW - Uozu, Japan	**TPSCo - Fab 7**	300mm Silicon Photonics: TPS45PHD	**4-12-27**	**
SB*18 - B6706	**TSSA - Fab 9**	SiGe BiCMOS 0.18um	**4-13-27**	**
CA18 - B6707	**NPB - Fab 3**	RFCMOS 0.18um	**4-27-27**	**11-04-27**
PH18M* - B6708	**NPB - Fab 3**	SiPho 0.18um	**5-11-27**	**1-03-28**
41st MPW - Tonami, Japan	**TPSCo - Fab 5**	CMOS 0.18u & 0.16u, PM, PM_SOI	**5-24-27**	**
SB*18 - B6709	**NPB - Fab 3**	SiGe BiCMOS 0.18um	**5-25-27**	**12-13-27**
SB*/CA13* - B6710	**NPB - Fab 3**	SiGe BiCMOS/RF CMOS 0.13um	**6-08-27**	**2-08-28**
PH18DA - B6711	**NPB - Fab 3**	SiPho 0.18um	**6-22-27**	**4-21-28**
SB*18 - B6712	**NPB - Fab 3**	SiGe BiCMOS 0.18um	**7-13-27**	**1-31-28**
CA18 - B6713	**NPB - Fab 3**	RFCMOS 0.18um	**7-27-27**	**1-07-28**
PH18M* - B6714	**NPB - Fab 3**	SiPho 0.18um	**8-10-27**	**4-03-28**
42nd MPW - Tonami, Japan	**TPSCo - Fab 5**	CMOS 0.18u & 0.16u, PM, PM_SOI	**8-23-27**	**
SB*18 - B6715	**NPB - Fab 3**	SiGe BiCMOS 0.18um	**8-24-27**	**3-02-28**
SBC18S6MPCA - B6716	**NPB - Fab 3**	SiGe BiCMOS 0.18um with PCM RF Switch	**9-14-27**	**
44th MPW - Uozu, Japan	**TPSCo - Fab 7**	CMOS, PM, RFCMOS & SiGe, 65nm : TPS65SLA/SLC, TPS65PMA/PMB/PMC/PMD/PMK/PML/MSA/MSB/MSC/MSD/MSK/MSL, TPS65RF, TPS65SG	**9-27-27**	**
SB*18 - B6717	**NPB - Fab 3**	SiGe BiCMOS 0.18um	**10-05-27**	**4-13-28**
45th MPW - Uozu, Japan	**TPSCo - Fab 7**	300mm Silicon Photonics: TPS45PHD	**10-25-27**	**
PH18M* - B6718	**NPB - Fab 3**	SiPho 0.18um	**10-26-27**	**6-19-28**
43rd MPW - Tonami, Japan	**TPSCo - Fab 5**	CMOS 0.18u & 0.16u, PM, PM_SOI	**11-24-27**	**

Notes: "Shuttles" (SH*) are run at Fab 2

* 0.13u MH – fab 2 Shuttle / MPW slots will be considered per needs

** Contact your Account Manager for details.

Please contact your customer account manager for additional information.

Fab2 - Tower Semiconductor 200mm wafer fabrication facility at Migdal Ha'emek, Israel

Fab3 - Tower Semiconductor 200mm wafer fabrication facility at Newport Beach, CA

Fab5 - Tower Semiconductor 200mm wafer fabrication facility at Tonami, Japan

Fab7 - Tower Semiconductor 300mm wafer fabrication facility at Uozu, Japan

Fab9 - Tower Semiconductor 200mm wafer fabrication facility at San Antonio, TX

Fab10 - Tower Semiconductor 300mm wafer fabrication facility at Agrate, Italy

Fab11 - Tower Semiconductor 300mm wafer fabrication facility at Rio Rancho, NM